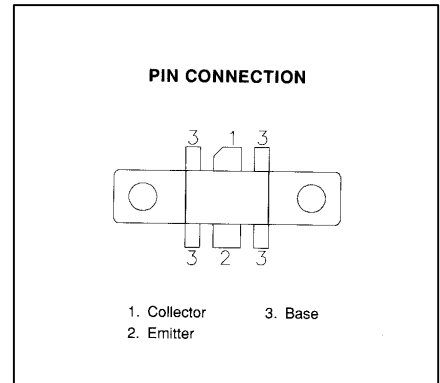
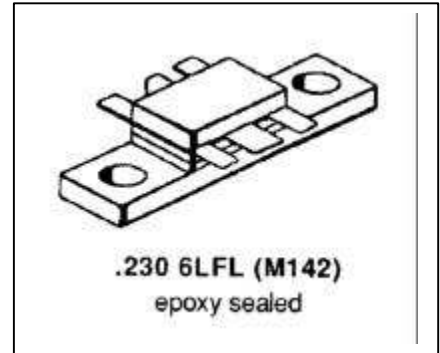


MS1454

**RF AND MICROWAVE TRANSISTORS
806-960 MHZ CELLULAR BASE STATIONS**

Features

- Gold Metallization
- Diffused Emitter Ballasting
- Internal Input Matching
- Designed for Linear Operation
- High Saturated Power Capability
- Common Emitter Configuration
- P_{OUT} 30 W MIN
- Gain 7.5 dB
- Efficiency 55% (Typ)
- 20:1 VSWR
- Overdrive Survivability 5 dB



DESCRIPTION:

The MS1454 gold/metallized epitaxial silicon NPN planar transistor uses diffused emitter ballast resistors for high linearity class AB operation in cellular base station applications.

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C)

| Symbol | Parameter | Value | Unit |
|-------------------|---------------------------|-------------|------|
| V _{CBO} | Collector-Base Voltage | 48 | V |
| V _{CEO} | Collector-Emitter Voltage | 25 | V |
| V _{EBO} | Emitter-Base Voltage | 3.5 | V |
| P _{DISS} | Total Power Dissipation | 88 | W |
| I _C | Collector Current | 7.5 | A |
| T _j | Junction Temperature | +200 | °C |
| T _{stg} | Storage Temperature | -65 to +150 | °C |

THERMAL DATA

| | | | |
|----------------------|----------------------------------|---|------|
| R _{TH(j-c)} | Junction-Case Thermal Resistance | 2 | °C/W |
|----------------------|----------------------------------|---|------|

ELECTRICAL SPECIFICATIONS (T_{case} = 25°C)
STATIC

| Symbol | Test Conditions | Value | | | Unit |
|-------------------------|--|------------|------------|------------|------------|
| | | Min. | Typ. | Max. | |
| BV_{CES} | I_C = 100 mA | 48 | 55 | --- | V |
| BV_{EBO} | I_E = 10 mA | 3.5 | 5 | --- | V |
| BV_{CEO} | I_C = 40 mA | 25 | 28 | --- | V |
| BV_{CER} | I_E = 40 mA R_{BE} = 100 Ω | 30 | 40 | --- | V |
| I_{CBO} | V_{CE} = 24 V | --- | --- | --- | mA |
| h_{FE} | V_{CE} = 20 V I_C = 2 A | 15 | 40 | 100 | --- |

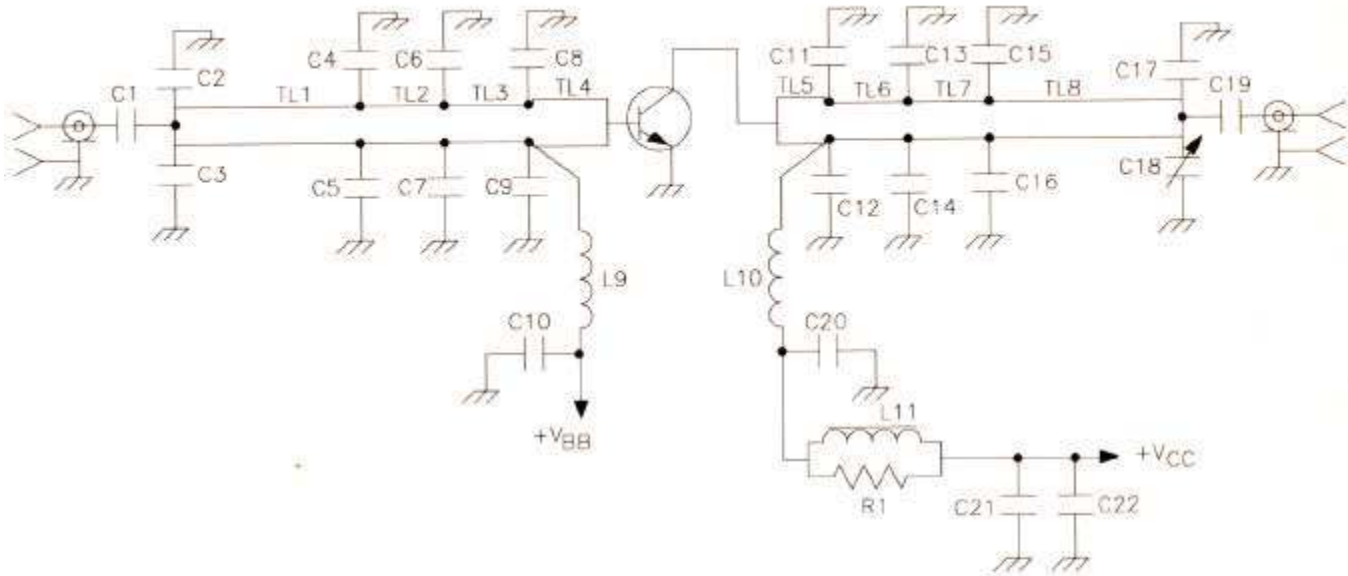
DYNAMIC

| Symbol | Test Conditions | Value | | | Unit |
|-------------------------|--|--|------------|------------|-------------|
| | | Min. | Typ. | Max. | |
| P_{OUT} | f = 860 MHz I_{CQ} = 60 mA V_{CE} = 25 V | 30 | --- | --- | W |
| η_C | f = 860 MHz I_{CQ} = 60 mA V_{CE} = 25 V | --- | 55 | --- | % |
| G_P | f = 860 MHz I_{CQ} = 60 mA V_{CE} = 25 V | 7.5 | 9 | --- | DB |
| C_{OB} | V_{CB} = 25 V f₀ = 1 MHz | --- | 42 | --- | pF |
| IMD₃ | P_{OUT} = 30 W PEP f₁ = 860.0 MHz f₂ = 860.1 MHz | --- | -35 | --- | dBc |
| VSWR₁ | VSWR = 20:1 V_{CE} = 25 V VSWR = 10:1 V_{CE} = 25 V ± 20% | NO DEGRADATION IN OUTPUT DEVICE | | | Typ. |
| VSWR₂ | VSWR = 5:1 V_{CE} = 25 V ± 20% P_{IN} = P_{IN} (norm) + 3 dB | NO DEGRADATION IN OUTPUT DEVICE | | | Typ. |
| OVD | P_{IN}(norm) = +5dB V_{CE} = 25 V P_{IN}(norm) = +5dB V_{CE} = 25 V ± 20% | NO DEGRADATION IN OUTPUT DEVICE | | | Typ. |

IMPEDANCE DATA

| Freq. | Z_{IN} (Ω) | Z_{CL} (Ω) |
|----------------|---------------------------|---------------------------|
| 800 MHz | 4.3 + j 5.8 | 3.5 + j 0.2 |
| 830 MHz | 3.2 + j 6.1 | 3.5 + j 0.1 |
| 860 MHz | 3.5 + j 7.1 | 2.9 – j 0.2 |
| 900 MHz | 5.3 + j 6.4 | 2.0 – j 0.6 |
| 915 MHz | 6.1 + j 6.3 | 3.2 – j 0.7 |
| 930 MHz | 9.4 + j 6.3 | 3.2 – j 1.1 |
| 945 MHz | 6.6 + j 3.0 | 3.3 – j 1.2 |
| 960 MHz | 5.9 + j 1.0 | 3.4 – j 1.5 |

TEST CIRCUIT

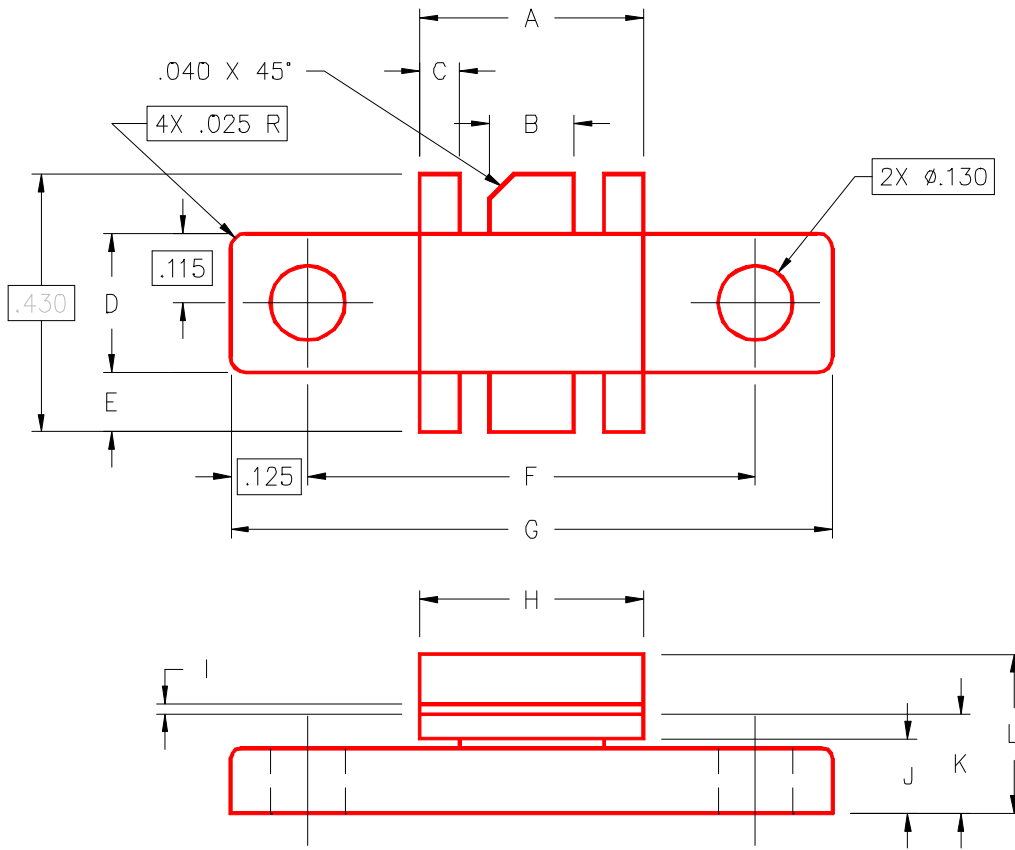


- C1, C19 : 33pF ATC 100B Chip Capacitor
- C2, C15 : 3.6pF ATC 100B Chip Capacitor
- C3 : 4.5pF ATC 100B Chip Capacitor
- C4, C16 : 5.0pF ATC 100B Chip Capacitor
- C5 : 2.9pF ATC 100B Chip Capacitor
- C6, C7 : 1.8pF ATC 100B Chip Capacitor
- C8, C9, C14 : 6.2pF ATC 100B Chip Capacitor
- C10, C22 : 300pF ATC 100B Chip Capacitor
- C11, C12

- C18 : .5 - 6.0pF Gigatrim Adjustable Capacitor
- C20 : 10pF ATC 100B Chip Capacitor
- C21 : 10 μ F (50V) Electrolytic Capacitor
- L9 : 4 Turns (tight) I.D. 120mil ENAM Cu 20 AWG
- L10 : 4 Turns (tight) I.D. 158mil ENAM Cu 18 AWG
- L11 : 1.5 Turns VK-200 Ferrite H.F. Choke
- TL1, TL8 : 964 x 85.69 mils (50 Ω /36.84')
- TL2, TL3 : 352 x 85.69 mils (50 Ω /13.46')
- TL4 : 222 x 109.03 mils (42.6 Ω /8.56')
- TL5 : 149 x 109.03 mils (42.6 Ω /5.74')
- TL6 : 334 x 85.69 mils (50 Ω /12.75')

PACKAGE MECHANICAL DATA

PACKAGE STYLE M142



| | MINIMUM INCHES/MM | MAXIMUM INCHES/MM | | MINIMUM INCHES/MM | MAXIMUM INCHES/MM |
|---|----------------------|----------------------|---|----------------------|----------------------|
| A | .355/9,02 | .365/9,27 | I | .004/0,10 | .006/0,15 |
| B | .115/2,92 | .125/3,18 | J | .120/3,05 | .130/3,30 |
| C | .075/1,91 | .085/2,16 | K | .160/4,06 | .180/4,57 |
| D | .225/5,72 | .235/5,97 | L | .230/5,84 | .260/6,60 |
| E | .090/2,29 | .110/2,79 | | | |
| F | .720/18,29 | .730/18,54 | | | |
| G | .970/24,64 | .980/24,89 | | | |
| H | .355/9,02 | .365/9,27 | | | |